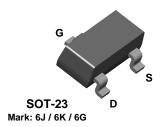


PN4391 PN4392 PN4393 MMBF4391 MMBF4392 **MMBF4393**





NOTE: Source & Drain are interchangeable

N-Channel Switch

This device is designed for low level analog switching, sample and hold circuits and chopper stabalized amplifiers. Sourced from Process 51. See J111 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	30	V
V _{GS}	Gate-Source Voltage	- 30	V
I _{GF}	Forward Gate Current	50	mA
T _J ,T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	N	Units	
		PN4391-4393	*MMBF4391-4393	
P _D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C
R _θ JC	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

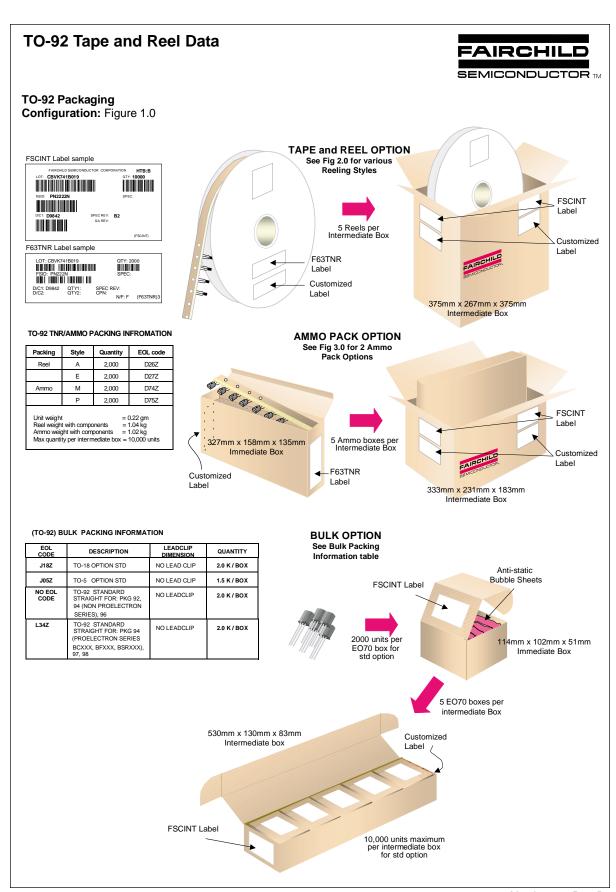
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

N-Channel Switch

(continued)

Symbol	Parameter Test Conditions				Max	Units
OFF CHAR	RACTERISTICS					
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = 1.0 \mu A, V_{DS} = 0$		- 30		V
I _{GSS}	Gate Reverse Current	$V_{GS} = -15 \text{ V}, V_{DS} = 0$			- 1.0	nA
		$V_{GS} = -15 \text{ V}, V_{DS} = 0, T_A = 0$	150°C		- 0.2	μΑ
V _{GS(off)}	Gate-Source Cutoff Voltage	$V_{DS} = 20 \text{ V}, I_{D} = 1.0 \text{ nA}$	4391	- 4.0	- 10	V
			4392 4393	- 2.0 - 0.5	- 5.0 - 3.0	V
V _{GS(f)}	Gate-Source Forward Voltage	I _G = 1.0 mA, V _{DS} = 0	4333	0.0	1.0	V
I _{D(off)}	Drain Cutoff Leakage Current	V _{DS} = 20 V, V _{GS} = - 12 V	4391		0.1	nA
2(0)		V _{DS} = 20 V, V _{GS} = -7.0 V	4392		0.1	nA
		$V_{DS} = 20 \text{ V}, V_{GS} = -5.0 \text{ V}$	4393		0.1	nA
		V _{DS} = 20 V, V _{GS} = - 12 V,	1201		0.2	μА
		$T_A = 150$ °C $V_{DS} = 20 \text{ V}, V_{GS} = -7.0 \text{ V},$	4391		0.2	μΛ
		T _A = 150°C	4392		0.2	μΑ
		$V_{DS} = 20 \text{ V}, V_{GS} = -5.0 \text{ V},$			0.0	
		T _A = 150°C	4393		0.2	μΑ
ON CHARA	ACTERISTICS					
I _{DSS}	Zero-Gate Voltage Drain Current*	$V_{DS} = 20 \text{ V}, V_{GS} = 0$	4391	50	150	mA
	j –	, 50	4392	25	75	mA
			4393	5.0	30	mA
$V_{DS(on)}$	Drain-Source On Voltage	$I_D = 12 \text{ mA}, V_{GS} = 0$	4391		0.4	V
		$I_D = 6.0 \text{ mA}, V_{GS} = 0$ $I_D = 3.0 \text{ mA}, V_{GS} = 0$	4392 4393		0.4 0.4	V
r _{DS(on)}	Drain-Source On Resistance	$I_D = 3.0 \text{ mA}, V_{GS} = 0$ $I_D = 1.0 \text{ mA}, V_{GS} = 0$	4391		30	Ω
108(011)	Brain Goards on Recicians	15 - 1.3 m, vgs - 3	4392		60	Ω
			4393		100	Ω
SMALL-SI	GNAL CHARACTERISTICS					
r _{ds(on)}	Drain-Source On Resistance	$V_{DS} = V_{GS} = 0$, f= 1.0 kHz	4391		30	Ω
rus(on)	Train Course on Resistance	1 55 1 65 6, 1 116 11.12	4392		60	Ω
			4393		100	Ω
Ciss	Input Capacitance	$V_{DS} = 20, V_{GS} = 0, f = 1.0 M$	Hz		14	pF
Crss	Reverse Transfer Capacitance	$V_{GS} = -12 \text{ V}, f = 1.0 \text{ MHz}$	4391		3.5	pF
		$V_{GS} = -7.0 \text{ V}, f = 1.0 \text{ MHz}$	4392		3.5 3.5	pF pF
		V _{GS} = - 5.0 V, f = 1.0 MHz	4393		3.3	Pi
SWITCHIN	NG CHARACTERISTICS	_			1	
t _r	Rise Time	$I_{D(on)} = 12 \text{ mA}$	4391		5.0	ns
		$I_{D(on)} = 6.0 \text{ mA}$	4392		5.0 5.0	ns ns
+,	Fall Time	$I_{D(on)} = 3.0 \text{ mA}$ $V_{GS(off)} = 12 \text{ V}$	4393		15	ns
t _f	i all lillie	$V_{GS(off)} = 12 \text{ V}$ $V_{GS(off)} = 6.0 \text{ V}$	4391 4392		20	ns
		$V_{GS(off)} = 6.0 \text{ V}$ $V_{GS(off)} = 3.0 \text{ V}$	4392		30	ns
t _{on}	Turn-On Time	$I_{D(0n)} = 12 \text{ mA}$	4391		15	ns
-0.1		$I_{D(on)} = 6.0 \text{ mA}$	4392		15	ns
		$I_{D(on)} = 3.0 \text{ mA}$	4393	<u></u>	15	ns
t _{off}	Turn-Off Time	V _{GS(off)} = 12 V	4391		20	ns
-011		$V_{GS(off)} = 6.0 \text{ V}$	4392		35	ns
		$V_{GS(off)} = 3.0 \text{ V}$			50	ns

*Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 1.0%

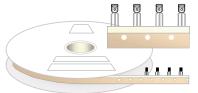


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TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)



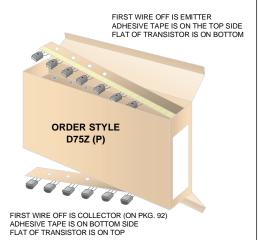
Style "A", D26Z, D70Z (s/h)

Machine Option "E" (J)

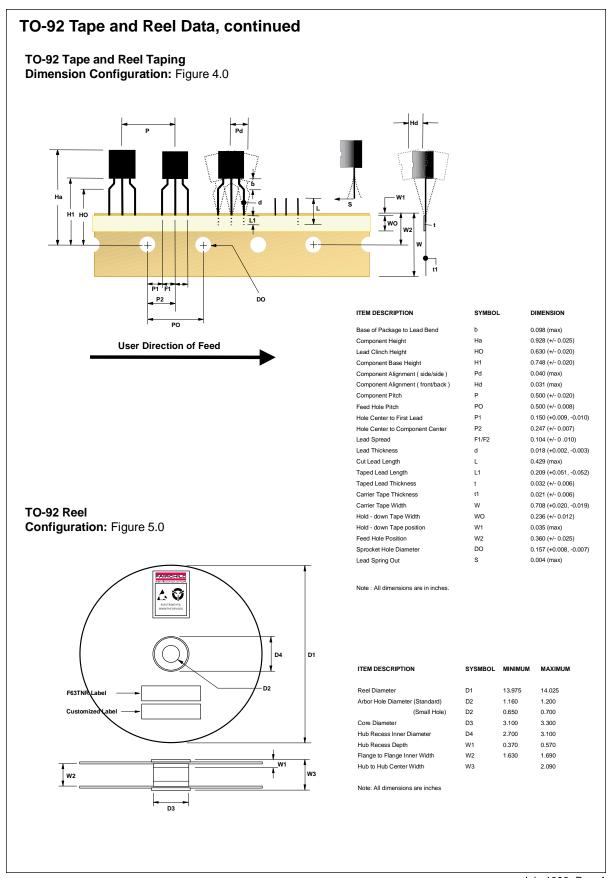
Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





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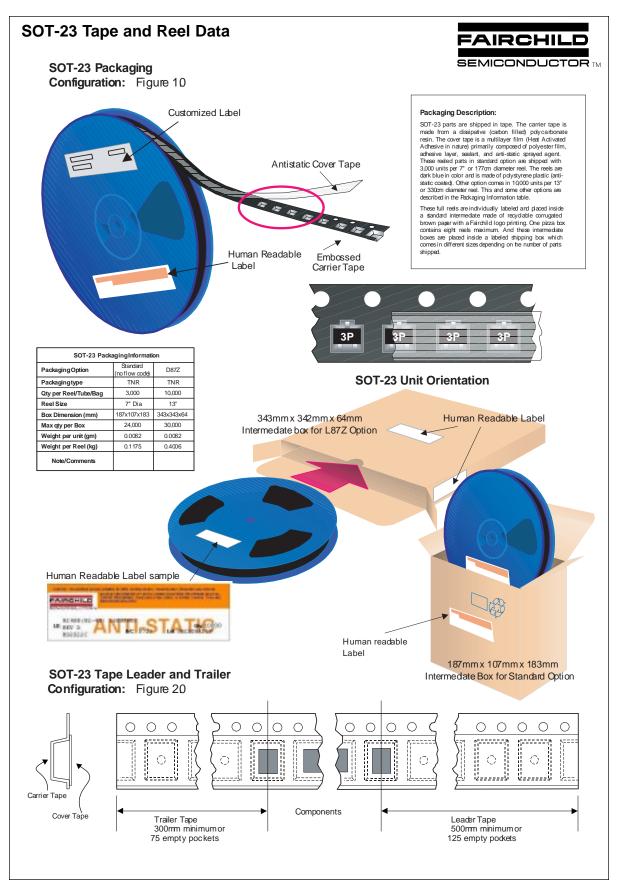


TO-92 Package Dimensions FAIRCHILD SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 B F В В В D D 2 В S С G Ε Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.

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0.095 0.084 2.13

January 2000, Rev. B

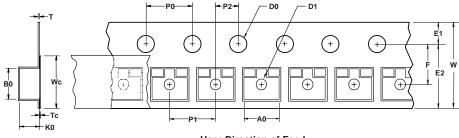


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SOT-23 Tape and Reel Data, continued

SOT-23 Embossed Carrier Tape

Configuration: Figure 3.0



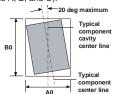
User Direction of Feed	

	Dimensions are in millimeter													
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
SOT-23 (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation



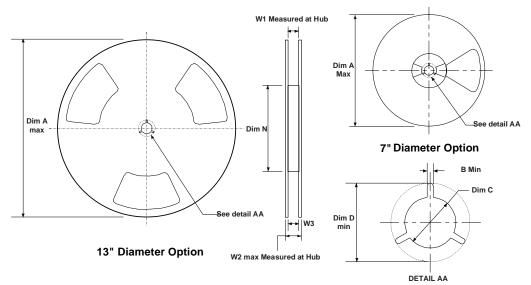
Sketch B (Top View)
Component Rotation



Sketch C (Top View)

Component lateral movement

SOT-23 Reel Configuration: Figure 4.0

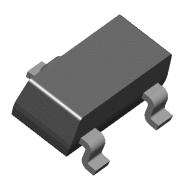


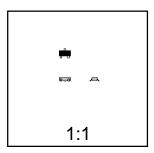
	Dimensions are in inches and millimeters								
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9

SOT-23 Package Dimensions



SOT-23 (FS PKG Code 49)

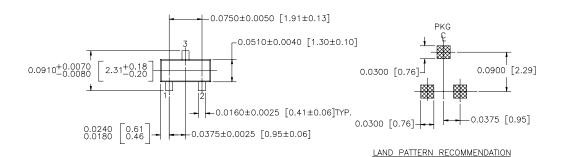


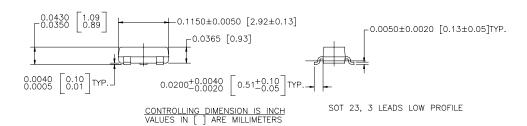


Scale 1:1 on letter size paper

Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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Rev. G